## AT25DF011



## 1-Mbit, 1.65V Minimum SPI Serial Flash Memory with Dual-Read Support

### PRELIMINARY DATASHEET

### Features

- Single 1.65V 3.6V Supply
- Serial Peripheral Interface (SPI) Compatible
  - Supports SPI Modes 0 and 3
  - Supports Dual Output Read
- 104MHz Maximum Operating Frequency
- Clock-to-Output (t<sub>V</sub>) of 6 ns
- Flexible, Optimized Erase Architecture for Code + Data Storage Applications
  - Uniform 256-Byte Page erase
  - Uniform 4-Kbyte Block Erase
  - Uniform 32-Kbyte Block Erase
  - Full Chip Erase
- Hardware Controlled Locking of Protected Sectors via WP Pin
  - 128-byte, One-Time Programmable (OTP) Security Register
    - 64 bytes factory programmed with a unique identifier
    - 64 bytes user programmable
- Flexible Programming
  - Byte/Page Program (1 to 256 Bytes)
- Fast Program and Erase Times
  - 1.5ms Typical Page Program (256 Bytes) Time
  - 50ms Typical 4-Kbyte Block Erase Time
  - 350ms Typical 32-Kbyte Block Erase Time
- Automatic Checking and Reporting of Erase/Program Failures
- Software Controlled Reset
- JEDEC Standard Manufacturer and Device ID Read Methodology
- Low Power Dissipation
  - 200nA Ultra Deep Power Down current (Typical)
  - 5µA Deep Power-Down Current (Typical)
  - 25uA Standby current (Typical)
  - 4.5mA Active Read Current (Typical)
- Endurance: 100,000 Program/Erase Cycles
- Data Retention: 20 Years
- Temperature Range:-10°C to +85°C (1.65V to 3.6V), -40°C to +85° (1.7V to 3.6V)
- Industry Standard Green (Pb/Halide-free/RoHS Compliant) Package Options
  - 8-lead SOIC (150-mil)
  - 8-pad Ultra Thin DFN (2 x 3 x 0.6 mm)
  - 8-lead TSSOP Package

## 1. Description

The Adesto<sup>®</sup> AT25DF011 is a serial interface Flash memory device designed for use in a wide variety of high-volume consumer based applications in which program code is shadowed from Flash memory into embedded or external RAM for execution. The flexible erase architecture of the AT25DF011, with its page erase granularity it is ideal for data storage as well, eliminating the need for additional data storage devices.

The erase block sizes of the AT25DF011 have been optimized to meet the needs of today's code and data storage applications. By optimizing the size of the erase blocks, the memory space can be used much more efficiently. Because certain code modules and data storage segments must reside by themselves in their own erase regions, the wasted and unused memory space that occurs with large sectored and large block erase Flash memory devices can be greatly reduced. This increased memory space efficiency allows additional code routines and data storage segments to be added while still maintaining the same overall device density.

The device also contains a specialized OTP (One-Time Programmable) Security Register that can be used for purposes such as unique device serialization, system-level Electronic Serial Number (ESN) storage, locked key storage, etc.

Specifically designed for use in many different systems, the AT25DF011 supports read, program, and erase operations with a wide supply voltage range of 1.65V to 3.6V. No separate voltage is required for programming and erasing.

## 2. Pin Descriptions and Pinouts

### Table 2-1. Pin Descriptions

Symbol	Name and Function	Asserted State	Туре
CS	<b>CHIP SELECT:</b> Asserting the CS pin selects the device. When the CS pin is deasserted, the device will be deselected and normally be placed in standby mode (not Deep Power-Down mode), and the SO pin will be in a high-impedance state. When the device is deselected, data will not be accepted on the SI pin. A high-to-low transition on the CS pin is required to start an operation, and a low-to-high transition is required to end an operation. When ending an internally self-timed operation such as a program or erase cycle, the device will not enter the standby mode until the completion of the operation.	Low	Input
SCK	<b>SERIAL CLOCK:</b> This pin is used to provide a clock to the device and is used to control the flow of data to and from the device. Command, address, and input data present on the SI pin is always latched in on the rising edge of SCK, while output data on the SO pin is always clocked out on the falling edge of SCK.	-	Input
SI (I/O <sub>0</sub> )	<b>SERIAL INPUT:</b> The SI pin is used to shift data into the device. The SI pin is used for all data input including command and address sequences. Data on the SI pin is always latched in on the rising edge of SCK. With the Dual-Output Read commands, the SI Pin becomes an output pin (I/O <sub>0</sub> ) in conjunction with other pins to allow two bits of data on (I/O <sub>1-0</sub> ) to be clocked out on every falling edge of SCK. To maintain consistency with the SPI nomenclature, the SI (I/O <sub>0</sub> ) pin will be referenced as the SI pin unless specifically addressing the Dual-I/O modes in which case it will be referenced as I/O <sub>0</sub> . Data present on the SI pin will be ignored whenever the device is deselected ( $\overline{CS}$ is deasserted).		Input/ Output



### Table 2-1. Pin Descriptions (Continued)

Symbol	Name and Function	Asserted State	Туре
SO (I/O <sub>1</sub> )	<b>SERIAL OUTPUT:</b> The SO pin is used to shift data out from the device. Data on the SO pin is always clocked out on the falling edge of SCK. With the Dual-Output Read commands, the SO Pin remains an output pin (I/O <sub>1</sub> ) in conjunction with other pins to allow two bits of data on (I/O <sub>1-0</sub> ) to be clocked out on every falling edge of SCK. To maintain consistency with the SPI nomenclature, the SO (I/O <sub>1</sub> ) pin will be referenced as the SO pin unless specifically addressing the Dual-I/O modes in which case it will be referenced as $I/O_1$ . The SO pin will be in a high-impedance state whenever the device is deselected ( $\overline{CS}$ is deasserted).	-	Input/ Output
WP	<b>WRITE PROTECT:</b> The $\overline{WP}$ pin controls the hardware locking feature of the device. Please refer to "Protection Commands and Features" on page 12 for more details on protection features and the $\overline{WP}$ pin. The $\overline{WP}$ pin is internally pulled-high and may be left floating if hardware controlled protection will not be used. However, it is recommended that the $\overline{WP}$ pin also be externally connected to V <sub>CC</sub> whenever possible.	Low	Input
HOLD	<b>HOLD:</b> The HOLD pin is used to temporarily pause serial communication without deselecting or resetting the device. While the HOLD pin is asserted, transitions on the SCK pin and data on the SI pin will be ignored, and the SO pin will be in a high-impedance state. The $\overline{CS}$ pin must be asserted, and the SCK pin must be in the low state in order for a Hold condition to start. A Hold condition pauses serial communication only and does not have an effect on internally self-timed operations such as a program or erase cycle. Please refer to "Hold" on page 27 for additional details on the Hold operation. The HOLD pin is internally pulled-high and may be left floating if the Hold function will not be used. However, it is recommended that the HOLD pin also be externally connected to V <sub>CC</sub> whenever possible.	Low	Input
V <sub>cc</sub>	<b>DEVICE POWER SUPPLY:</b> The V <sub>CC</sub> pin is used to supply the source voltage to the device. Operations at invalid V <sub>CC</sub> voltages may produce spurious results and should not be attempted.	-	Power
GND	<b>GROUND:</b> The ground reference for the power supply. GND should be connected to the system ground.	-	Power

### Figure 2-1. 8-SOIC Top View

CS 🖂	1	8	
SO 🖂	2	7	- HOLD
WP 🗀	3	6	□ SCK
GND 🗔	4	5	🗆 SI

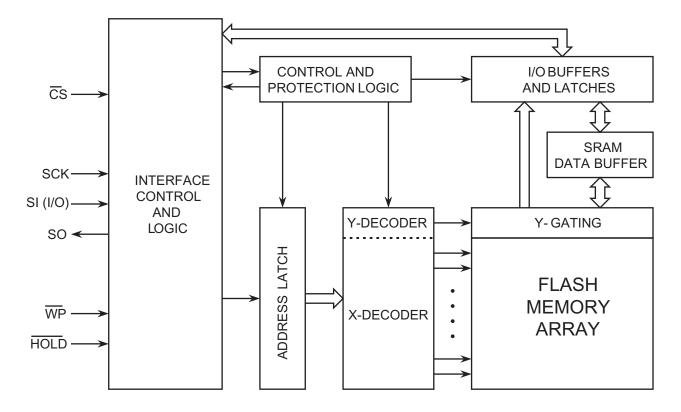
## Figure 2-3. 8-UDFN (Top View)

CS	1	8	VCC
SO		7	HOLD
$\overline{WP}$	3	6	SCK
GND	4	5	SI

### Figure 2-2. 8-TSSOP Top View

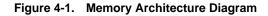
CS 🗀	1	8	
SO 🖂	2	7	
WP 🗆	3	6	□ SCK
GND 🖂	4	5	🗀 SI

## 4. Memory Array



To provide the greatest flexibility, the memory array of the AT25DF011 can be erased in three levels of granularity including a full chip erase. The size of the erase blocks is optimized for both code and data storage applications, allowing both code and data segments to reside in their own erase regions. The Memory Architecture Diagram illustrates the breakdown of each erase level.





**Block Erase Detail** 

Block Erase (52h Command)         Block Address Range         Page Program (02h Command)         Page Address Range           32KB         4KB 4KB 01EFFFh = 01F000h 4KB 01DFFFh = 01D000h 4KB 01DFFFh = 01D000h 4KB 01DFFFh = 01D000h 4KB 01DFFFh = 01D000h 4KB 01DFFFh = 01B000h 4KB 01BFFFh = 01B000h 4KB 01BFFFh = 01B000h 4KB 01BFFFh = 01B000h 4KB 01BFFFh = 01B000h 256 Bytes 01FBFFh = 01FB00 256 Bytes 000FFFh = 01FB00 256 Bytes 000FFFh = 00FB00 256 Bytes 000FFFh = 000E00 256 Bytes 000FFFh = 000B00 256 B	32KB	4KB		1-256 Byte	
(S2h Command)         Range         (Q2h Command)         Range           32KB         4KB         01FFFFh - 01F000h         256 Bytes         01FFFFh - 01F000h           32KB         4KB         01DFFFh - 01E000h         256 Bytes         01FFFFh - 01F000h           4KB         01DFFFh - 01E000h         256 Bytes         01FFFFh - 01F000         256 Bytes         01FFFFh - 01F000h           4KB         01DFFFh - 01B000h         256 Bytes         01FFFFh - 01F000         256 Bytes         01FFFFh - 01F000           4KB         01AFFFh - 01B000h         256 Bytes         01FBFFh - 01F000         256 Bytes         01FBFFh - 01F000           4KB         01AFFFh - 01900h         256 Bytes         01FBFFh - 01F000         256 Bytes         01FBFFh - 01F000           4KB         018FFFh - 01900h         256 Bytes         01FBFFh - 01F000         256 Bytes         01FBFFh - 01F000           4KB         018FFFh - 01700h         256 Bytes         01FBFFh - 01F000         256 Bytes         01FAFFh - 01F000           32KB         4KB         015FFFh - 01500h         256 Bytes         01F4FFh - 01F000         256 Bytes         01F4FFh - 01F000           4KB         012FFFh - 012000h         256 Bytes         01F4FFh - 01F200         256 Bytes         01F4FFh - 01F200		Block Erase	Block Address		Page Address
32KB         4KB         01FFFFh = 01F000h         256 Bytes         01FFFFh = 01F000h           32KB         4KB         01EFFFh = 01C000h         256 Bytes         01FEFFh = 01F000h           32KB         4KB         01CFFFh = 01C000h         256 Bytes         01FEFFh = 01F000h           4KB         01BFFFh = 01B000h         256 Bytes         01FAFFh = 01F000h         256 Bytes         01FAFFh = 01F000h           4KB         01BFFFh = 01B000h         256 Bytes         01FAFFh = 01F000h         256 Bytes         01FAFFh = 01F000h           4KB         013FFFh = 018000h         256 Bytes         01FAFFh = 01F000h         256 Bytes         01FAFFh = 01F000h           4KB         013FFFh = 017000h         256 Bytes         01F6FFh = 01F000h         256 Bytes         01F6FFh = 01F000h           4KB         015FFFh = 015000h         256 Bytes         01F6FFh = 01F000h         256 Bytes         01F6FFh = 01F000h           4KB         013FFFh = 013000h         256 Bytes         01F3FFh = 01F2000h         256 Bytes         01F3FFh = 01F2000h           4KB         013FFFh = 013000h         256 Bytes         01F3FFh = 01F2000h         256 Bytes         01F3FFh = 01F2000h           4KB         015FFFh = 011000h         256 Bytes         01F3FFh = 01F2000         256 Bytes         000F	(52h Command)	(20h Command)	Range		•
4KB         01EFFFh         01E000h         256 Bytes         01FEFFh         01FDFFh         01F000h           32KB         4KB         01CFFFh         01000h         256 Bytes         01FCFFh         01F000h           4KB         01BFFFh         01B000h         256 Bytes         01FDFFh         01F000h           4KB         01BFFFh         019000h         256 Bytes         01FBFFh         01F000h           4KB         01BFFFh         019000h         256 Bytes         01FBFFh         01F000h           4KB         018FFFh         019000h         256 Bytes         01F3FFh         01F3FFh           4KB         016FFFh         017000h         256 Bytes         01F3FFh         01F3FFh         01F3FFh           4KB         016FFFh         015000h         256 Bytes         01F3FFh         01F3FFh <td></td> <td>. ,</td> <td>· · · · · · · · · · · · · · · · ·</td> <td>. ,</td> <td></td>		. ,	· · · · · · · · · · · · · · · · ·	. ,	
32KB         4KB         01DFFFh - 01D000h         256 Bytes         01FDFFh - 01FD00           32KB         4KB         01BFFFh - 01B000h         256 Bytes         01FDFFh - 01FD00           4KB         01BFFFh - 01B000h         256 Bytes         01FAFFh - 01FD00           4KB         019FFFh - 019000h         256 Bytes         01FAFFh - 01FD00           4KB         019FFFh - 019000h         256 Bytes         01FAFFh - 01FD00           4KB         017FFFh - 017000h         256 Bytes         01FFFFh - 01F900           4KB         016FFFh - 015000h         256 Bytes         01FFFFh - 01F900           4KB         016FFFh - 015000h         256 Bytes         01FFFFh - 01F900           4KB         015FFFh - 015000h         256 Bytes         01FFFFh - 01F200           4KB         014FFFh - 014000h         256 Bytes         01FFFFh - 01F200           4KB         013FFFh - 013000h         256 Bytes         01FFFh - 01F200           4KB         010FFFh - 011000h         256 Bytes         01FFFh - 01F200           4KB         010FFFh - 010000h         1         1           4KB         00DFFFh - 000000h         256 Bytes         00DFFFh - 000000h           4KB         00DFFFh - 000000h         256 Bytes         0000FFFh - 00000	-				
32KB         4KB         01CFFFh - 01C000h         256 Bytes         01FCFFh - 01FC00           4KB         01AFFFh - 01B000h         256 Bytes         01FAFFh - 01FB00           4KB         01AFFFh - 019000h         256 Bytes         01FAFFh - 01FB00           4KB         013FFFh - 019000h         256 Bytes         01FAFFh - 01FB00           4KB         013FFFh - 019000h         256 Bytes         01FAFFh - 01FB00           4KB         013FFFh - 017000h         256 Bytes         01F3FFh - 01F800           4KB         013FFFh - 016000h         256 Bytes         01F3FFh - 01F800           4KB         013FFFh - 016000h         256 Bytes         01F3FFh - 01F800           4KB         013FFFh - 014000h         256 Bytes         01F3FFh - 01F300           4KB         013FFFh - 012000h         256 Bytes         01F3FFh - 01F300           4KB         013FFFh - 012000h         256 Bytes         01F3FFh - 01F300           4KB         013FFFh - 01000h         256 Bytes         01F3FFh - 01F200           4KB         016FFFh - 00000h         256 Bytes         000FFFh - 00000h           4KB         006FFFh - 00000h         256 Bytes         0000FFh - 00000h           32KB         4KB         000FFFh - 00000h         256 Bytes					
32KB         4KB         01BFFFh         01B00h         256 Bytes         01FBFFh         01FB00           4KB         013FFFh         01900h         256 Bytes         01FAFFh         01FFFh         01FAFFh					
4KB         018FFh         018000h         256 Bytes         01FBFh         01FB00           4KB         014FFFh         019000h         256 Bytes         01FAFFh         01F3000 <td>32KB</td> <td></td> <td></td> <td></td> <td>01FCFFh - 01FC00h</td>	32KB				01FCFFh - 01FC00h
4KB         019FFFh         01900h         256 Bytes         01F9FFh         01F900           4KB         018FFFh         01800h         256 Bytes         01F8FFh         01F7FFh         01F300h         256 Bytes         01F7FFh         01F600         256 Bytes         01F8FFh         01F6FFh         01F600         256 Bytes         01F8FFh         01F6FFh         01F300         256 Bytes         01F3FFh         01F300         256 Bytes         000FFFh         000000         256 Bytes         000FFFh	0LILD			256 Bytes	01FBFFh – 01FB00h
4KB         018FFFh         01800h         256 Bytes         01F8FFh         01F800           32KB         4KB         016FFFh         01700h         256 Bytes         01F7FFh         01F700           32KB         4KB         016FFFh         01600h         256 Bytes         01F6FFh         01F6FFh         01F600           4KB         013FFFh         01400h         256 Bytes         01F3FFh         01F300		4KB	01AFFFh – 01A000h	256 Bytes	01FAFFh – 01FA00h
32KB         4KB         017FFFh         017000h         256 Bytes         01F7FFh         01F7FFh         01F7000h           32KB         4KB         015FFFh         015000h         256 Bytes         01F3FFFh         01F3FFFh         01F3FFFh         01F3FFh         01F3000         256 Bytes         000DFFh<		4KB	019FFFh – 019000h	256 Bytes	01F9FFh - 01F900h
32KB         4KB         016FFFh         016000h         256 Bytes         01F6FFh         01F600           32KB         4KB         013FFFh         013000h         256 Bytes         01F4FFh         01F3FFh         01F4FFh         01F3FFh         01F5Fh         01F2Fh         01F2FFh         01F2FFh         01F3FFh         01F5Fh         0000FFh         000FFFh         0000FFh         0000FFh         0000FFh         0000FFh         0000FFFh         0000FFFh         0000FFFh		4KB	018FFFh – 018000h	256 Bytes	01F8FFh - 01F800h
32KB         4KB         015FFFh         015000h         256 Bytes         01F5FFh         01F5FPh         01F5F0           32KB         4KB         013FFFh         013000h         256 Bytes         01F4FFh         01F3FFh         01F5Fh         000FFFh         00FFFh         000FFFh         0000FFh         000FFFh         0000FFh         0000FFh         0000FFFh         0000FFh         0000FFFh         0000FFFh         0000C00         256 Bytes         0003FFFh         0003FFFh         0003FFFh         000300h </td <td></td> <td>4KB</td> <td>017FFFh – 017000h</td> <td>256 Bytes</td> <td>01F7FFh - 01F700h</td>		4KB	017FFFh – 017000h	256 Bytes	01F7FFh - 01F700h
32KB         4KB         014FFFh         014000h         256 Bytes         01F4FFh         01F400           4KB         013FFFh         013000h         256 Bytes         01F3FFh         00DFFFh         000FFFh         000FFFh         000FFFh         000FFFh         000DFFh         0003FFFh         0003FFFh <td></td> <td>4KB</td> <td>016FFFh – 016000h</td> <td>256 Bytes</td> <td>01F6FFh - 01F600h</td>		4KB	016FFFh – 016000h	256 Bytes	01F6FFh - 01F600h
32KB         4KB         013FFFh         01300h         256 Bytes         01F3FFh         00DFFFh         00D00h         256 Bytes         000DFFh         000DF000         256 Bytes         0000FFFh         00000h         256 Bytes         0003FFFh         000300h         256 Bytes         0003FFFh         000300h         256 Bytes         0003FFFh         000300h         256 Bytes         0003FFFh         000300h		4KB	015FFFh - 015000h	256 Bytes	01F5FFh - 01F500h
4KB         013FFFh         013000h         256 Bytes         01F3FFh         01F300           4KB         012FFFh         012000h         256 Bytes         01F2FFh         01F1FFh         01F1Fh         00FFFh         00F0F0h         1F         1F         00FFFh         000FFh         000DFFh         000DFFFh         000DFFh         000DFF	2017 0	4KB	014FFFh – 014000h	256 Bytes	01F4FFh - 01F400h
4KB         011FFFh         011000h         256 Bytes         01F1FFh         01F100           4KB         010FFFh         010000h         i	32KB	4KB	013FFFh – 013000h	256 Bytes	01F3FFh - 01F300h
4KB         010FFFh         010000h         i           4KB         00FFFh         00F000h         256 Bytes         000EFFh         0000DFFh           4KB         00EFFFh         00D000h         256 Bytes         000EFFh         0000DFFh         0000DFFh         000DFFh         000SFFh         000SFFh         000SFFh         000SFFh         000SFFh         000SFFh         000SFFh         000SFFh         000SFFh         <		4KB	012FFFh – 012000h	256 Bytes	01F2FFh - 01F200h
4KB         00FFFh         00F000h         :           4KB         00EFFh         00EFFh         00EFFh         000EFFh         00EFFh <t< td=""><td></td><td>4KB</td><td>011FFFh – 011000h</td><td>256 Bytes</td><td>01F1FFh - 01F100h</td></t<>		4KB	011FFFh – 011000h	256 Bytes	01F1FFh - 01F100h
4KB         00EFFFh         00E000h         256 Bytes         000EFFh         000E000           4KB         00DFFFh         00000h         256 Bytes         000DFFh         000FFh         000DFFh         000FFh         000DFFh         000FFh         000FFh         000FFh         000DFFh         000FFh         00		4KB	010FFFh – 010000h	•	
4KB         00DFFFh         00D000h         256 Bytes         000DFFh         000000000000000000000000000000000000		4KB	00FFFFh - 00F000h	:	
4KB         00DFFFh         00D000h         256 Bytes         000DFFh         000000000000000000000000000000000000		4KB	00EFFFh - 00E000h	256 Bytes	000EFFh - 000E00h
32KB         4KB         00CFFFh - 00C000h         256 Bytes         000CFFh - 000C00           4KB         00BFFFh - 00B000h         256 Bytes         000BFFh - 000B00           4KB         00AFFFh - 004000h         256 Bytes         000AFFh - 000000           4KB         003FFFh - 009000h         256 Bytes         000AFFh - 000900h           4KB         003FFFh - 009000h         256 Bytes         0003FFh - 000900h           4KB         003FFFh - 007000h         256 Bytes         0003FFh - 000700h           4KB         006FFFh - 006000h         256 Bytes         0007FFh - 000700h           4KB         006FFFh - 005000h         256 Bytes         0007FFh - 000700h           32KB         4KB         004FFFh - 005000h         256 Bytes         0005FFh - 000500h           32KB         4KB         004FFFh - 003000h         256 Bytes         0003FFh - 000300h           32KB         4KB         003FFFh - 003000h         256 Bytes         0003FFh - 000300h           32KB         4KB         003FFFh - 003000h         256 Bytes         0003FFh - 000300h           4KB         003FFFh - 003000h         256 Bytes         0003FFh - 000300h         256 Bytes           4KB         002FFFh - 002000h         256 Bytes         0003FFh - 000200h		4KB	00DFFFh - 00D000h		000DFFh - 000D00h
32KB         4KB         00BFFFh         00B000h         256 Bytes         000BFFh         0000B00           4KB         00AFFFh         004000h         256 Bytes         000AFFh         0004FFh         0005FFh         0005FFh         0005FFh         0004FFh         0003FFh         0003FFh         0003FFh         0003FFh         0003FFh         0002FFh         0002FFh <td>001/10</td> <td></td> <td>4</td> <td></td> <td>000CFFh - 000C00h</td>	001/10		4		000CFFh - 000C00h
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4KB         009FFFh         009000h         256 Bytes         0009FFh         000900h           4KB         008FFFh         00800h         256 Bytes         0008FFh         0007FFh         000000h         256 Bytes         0007FFh         0000000           4KB         006FFFh         006000h         256 Bytes         0005FFFh         000500h         256 Bytes         0005FFFh         000500h         256 Bytes         0005FFFh         000500h         256 Bytes         0004FFh         0004FFh         0004FFh         0004FFh         0004FFh         0004FFh         0003FFFh         0002FFh	-	4KB	00AFFFh - 00A000h	,	000AFFh - 000A00h
4KB         008FFFh         008000h         256 Bytes         0008FFh         000800h           4KB         007FFFh         007000h         256 Bytes         0007FFh         000700h           4KB         006FFFh         006000h         256 Bytes         0006FFh         0006FFh         0006FFh           4KB         005FFFh         005FFFh         005000h         256 Bytes         0005FFh         0005FFh         00000h           4KB         004FFFh         004000h         256 Bytes         0004FFh         0004000           4KB         003FFFh         003000h         256 Bytes         0003FFh         0003000           4KB         002FFFh         002000h         256 Bytes         0002FFh         0002FFh           4KB         001FFFh         001000h         256 Bytes         0002FFh         0002FFh	-		4		0009FFh - 000900h
4KB         007FFFh         007000h         256 Bytes         0007FFh         000700h           4KB         006FFFh         006000h         256 Bytes         0006FFh         0006FFh         0006FFh         0006FFh         0006FFh         0006FFh         0006FFh         0006FFh         00006FFh         0006FFh         00006FFh         00006FFh         00006FFh         00006FFh         00006FFh         00006FFh         000000000         000000000000000000000000000000000000	-				
4KB         006FFFh         006000h         256 Bytes         0006FFh         0006000           4KB         005FFFh         005FFFh         0005FFh         00004FFh         0004FFh         0004FFh         0004FFh         0004FFh         0003FFh         0003FFh         0003FFh         0003FFh         0003FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0001FFh         0001FFh </td <td></td> <td></td> <td>-</td> <td></td> <td>0007FFh - 000700h</td>			-		0007FFh - 000700h
4KB         005FFFh         005000h         256 Bytes         0005FFh         000500h           32KB         4KB         004FFFh         004000h         256 Bytes         0004FFh         00000h         256 Bytes         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0001FFh         0001FFh <td>-</td> <td></td> <td></td> <td>-</td> <td></td>	-			-	
32KB         4KB         004FFFh         004000h         256 Bytes         0004FFh         000400           4KB         003FFFh         003000h         256 Bytes         0003FFh         0003FFh         0003FFh         0003FFh         0003FFh         0003FFh         0003FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0002FFh         0001FFh	-			· · · · ·	
32KB         4KB         003FFFh         003000h         256 Bytes         0003FFh         000300           4KB         002FFFh         002000h         256 Bytes         0002FFh         0002FFh         0002FFh         0002FFh         0001FFh				· · · · · · · · · · · · · · · · · · ·	
4KB         002FFFh         - 002000h         256 Bytes         0002FFh         - 000200           4KB         001FFFh         - 001000h         256 Bytes         0001FFh         - 000100	32KB		4	<b>/</b> /	
4KB 001FFFh – 001000h 256 Bytes 0001FFh – 000100	-				
	-				
	-	4KB	000FFFh - 000000h	256 Bytes	0000FFh - 000000h

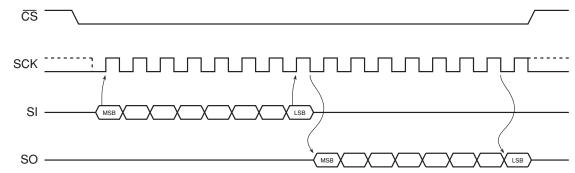
Page Program Detail

## 5. Device Operation

The AT25DF011 is controlled by a set of instructions that are sent from a host controller, commonly referred to as the SPI Master. The SPI Master communicates with the AT25DF011 via the SPI bus which is comprised of four signal lines: Chip Select ( $\overline{CS}$ ), Serial Clock (SCK), Serial Input (SI), and Serial Output (SO).

The SPI protocol defines a total of four modes of operation (mode 0, 1, 2, or 3) with each mode differing in respect to the SCK polarity and phase and how the polarity and phase control the flow of data on the SPI bus. The AT25DF011 supports the two most common modes, SPI Modes 0 and 3. The only difference between SPI Modes 0 and 3 is the polarity of the SCK signal when in the inactive state (when the SPI Master is in standby mode and not transferring any data). With SPI Modes 0 and 3, data is always latched in on the rising edge of SCK and always output on the falling edge of SCK.





### 5.1 Dual Output Read

The ATx features a Dual-Output Read mode that allow two bits of data to be clocked out of the device every clock cycle to improve throughput. To accomplish this, both the SI and SO pins are utilized as outputs for the transfer of data bytes. With the Dual-Output Read Array command, the SI pin becomes an output along with the SO pin.

## 6. Commands and Addressing

A valid instruction or operation must always be started by first asserting the  $\overline{CS}$  pin. After the  $\overline{CS}$  pin has been asserted, the host controller must then clock out a valid 8-bit opcode on the SPI bus. Following the opcode, instruction dependent information such as address and data bytes would then be clocked out by the host controller. All opcode, address, and data bytes are transferred with the most-significant bit (MSB) first. An operation is ended by deasserting the  $\overline{CS}$  pin.

Opcodes not supported by the AT25DF011 will be ignored by the device and no operation will be started. The device will continue to ignore any data presented on the SI pin until the start of the next operation ( $\overline{CS}$  pin being deasserted and then reasserted). In addition, if the  $\overline{CS}$  pin is deasserted before complete opcode and address information is sent to the device, then no operation will be performed and the device will simply return to the idle state and wait for the next operation.

Addressing of the device requires a total of three bytes of information to be sent, representing address bits A23-A0. Since the upper address limit of the AT25DF011 memory array is 01FFFFh, address bits A23-A17 are always ignored by the device.

Command	Opcode		Clock Frequency	Address Bytes	Dummy Bytes	Data Bytes
Read Commands						,
Dood Arrow	0Bh	0000 1011	Up to 104 MHz	3	1	1+
Read Array	03h	0000 0011	Up to 33 MHz $^{(1)}$	3	0	1+
Dual Output Read		0011 1011	Up to 50 MHz	3	1	1+
Program and Erase Commands	1		1			I
Page Erase	81h	1000 0001	Up to 104 MHz	3	0	0
Block Erase (4 Kbytes)	20h	0010 0000	Up to 104 MHz	3	0	0
Plack Eraca (22 Khutaa)	52h	0101 0010	Up to 104 MHz	3	0	0
Block Erase (32 Kbytes)	D8h	1101 1000	Up to 104 MHz	3	0	0

### Table 6-1. Command Listing



#### Table 6-1. Command Listing

Command		Opcode	Clock Frequency	Address Bytes	Dummy Bytes	Data Bytes
Chip Erase		0110 0000	Up to 104 MHz	0	0	0
	C7h	1100 0111	Up to 104 MHz	0	0	0
Chip Erase (Legacy Command)	62h	0110 0010	Up to 104 MHz	0	0	0
Byte/Page Program (1 to 256 Bytes)	02h	0000 0010	Up to 104 MHz	3	0	1+
Protection Commands						
Write Enable	06h	0000 0110	Up to 104 MHz	0	0	0
Write Disable	04h	0000 0100	Up to 104 MHz	0	0	0
Security Commands	-!		1			
Program OTP Security Register	9Bh	1001 1011	Up to 104 MHz	3	0	1+
Read OTP Security Register	77h	0111 0111	Up to 104 MHz	3	2	1+
Status Register Commands	-					
Read Status Register	05h	0000 0101	Up to 104 MHz	0	0	1+
Write Status Register Byte 1	01h	0000 0001	Up to 104 MHz	0	0	1
Write Status Register Byte 2	31h	0011 0001	Up to 104 MHz	0	0	1
Miscellaneous Commands			1	1	1	1
Reset	F0h	1111 0000	Up to 104 MHz	0	0	1(D0h)
Read Manufacturer and Device ID	9Fh	1001 1111	Up to 104 MHz	0	0	1 to 4
Read ID (Legacy Command)	15h	0001 0101	Up to 104 MHz	0	0	2
Deep Power-Down	B9h	1011 1001	Up to 104 MHz	0	0	0
Resume from Deep Power-Down	ABh	1010 1011	Up to 104 MHz	0	0	0
Ultra Deep Power-Down	79h	0111 1001	Up to 104 MHz	0	0	0

1. Varies by voltage range. See Table 13.4 "AC Characteristics - Maximum Clock Frequencies".

## 7. Read Commands

### 7.1 Read Array

The Read Array command can be used to sequentially read a continuous stream of data from the device by simply providing the clock signal once the initial starting address is specified. The device incorporates an internal address counter that automatically increments every clock cycle.

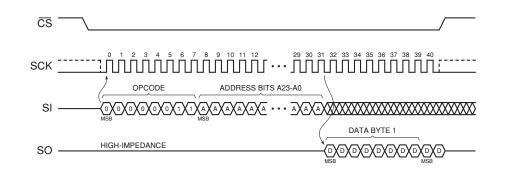
Two opcodes (0Bh and 03h) can be used for the Read Array command. The use of each opcode depends on the maximum clock frequency that will be used to read data from the device. The 0Bh opcode can be used at any clock frequency up to the maximum specified by  $f_{CLK}$ , and the 03h opcode can be used for lower frequency read operations up to the maximum specified by  $f_{RDLF}$ .



To perform the Read Array operation, the  $\overline{CS}$  pin must first be asserted and the appropriate opcode (0Bh or 03h) must be clocked into the device. After the opcode has been clocked in, the three address bytes must be clocked in to specify the starting address location of the first byte to read within the memory array. Following the three address bytes, an additional dummy byte needs to be clocked into the device if the 0Bh opcode is used for the Read Array operation.

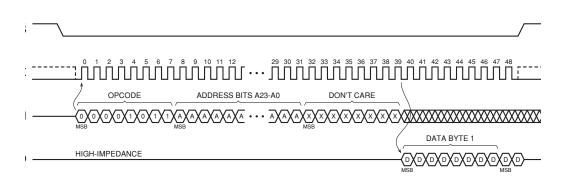
After the three address bytes (and the dummy byte if using opcode 0Bh) have been clocked in, additional clock cycles will result in data being output on the SO pin. The data is always output with the MSB of a byte first. When the last byte (01FFFFh) of the memory array has been read, the device will continue reading back at the beginning of the array (000000h). No delays will be incurred when wrapping around from the end of the array to the beginning of the array.

Deasserting the  $\overline{CS}$  pin will terminate the read operation and put the SO pin into high-impedance state. The  $\overline{CS}$  pin can be deasserted at any time and does not require a full byte of data be read.



#### Figure 7-1. Read Array - 03h Opcode





## 7.2 Dual-Output Read Array

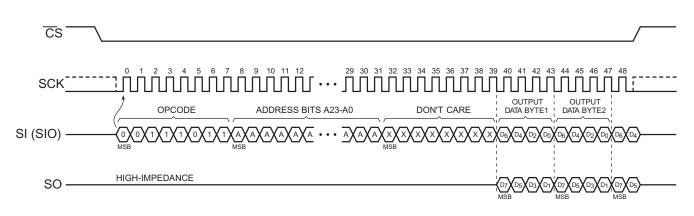
The Dual-Output Read Array command is similar to the standard Read Array command and can be used to sequentially read a continuous stream of data from the device by simply providing the clock signal once the initial starting address has been specified. Unlike the standard Read Array command, however, the Dual-Output Read Array command allows two bits of data to be clocked out of the device on every clock cycle, rather than just one.

The Dual-Output Read Array command can be used at any clock frequency, up to the maximum specified by  $f_{RDDO}$ . To perform the Dual-Output Read Array operation, the  $\overline{CS}$  pin must first be asserted and then the opcode 3Bh must be clocked into the device. After the opcode has been clocked in, the three address bytes must be clocked in to specify the location of the first byte to read within the memory array. Following the three address bytes, a single dummy byte must also be clocked into the device.

After the three address bytes and the dummy byte have been clocked in, additional clock cycles will result in data being output on both the SO and SIO pins. The data is always output with the MSB of a byte first and the MSB is always output on the SO pin. During the first clock cycle, bit seven of the first data byte is output on the SO pin, while bit six of the same data byte is output on the SIO pin. During the next clock cycle, bits five and four of the first data byte are output on the SO



and SIO pins, respectively. The sequence continues with each byte of data being output after every four clock cycles. When the last byte (01FFFFh) of the memory array has been read, the device will continue reading from the beginning of the array (000000h). No delays will be incurred when wrapping around from the end of the array to the beginning of the array.Deasserting the  $\overline{CS}$  pin will terminate the read operation and put the SO and SIO pins into a high-impedance state. The  $\overline{CS}$  pin can be deasserted at any time and does not require that a full byte of data be read.



#### Figure 7-3. Dual-Output Read Array

## 8. Program and Erase Commands

### 8.1 Byte/Page Program

The Byte/Page Program command allows anywhere from a single byte of data to 256 bytes of data to be programmed into previously erased memory locations. An erased memory location is one that has all eight bits set to the logical "1" state (a byte value of FFh). Before a Byte/Page Program command can be started, the Write Enable command must have been previously issued to the device (see "Write Enable" on page 12) to set the Write Enable Latch (WEL) bit of the Status Register to a logical "1" state.

To perform a Byte/Page Program command, an opcode of 02h must be clocked into the device followed by the three address bytes denoting the first byte location of the memory array to begin programming at. After the address bytes have been clocked in, data can then be clocked into the device and will be stored in an internal buffer.

If the starting memory address denoted by A23-A0 does not fall on an even 256-byte page boundary (A7-A0 are not all 0), then special circumstances regarding which memory locations to be programmed will apply. In this situation, any data that is sent to the device that goes beyond the end of the page will wrap around back to the beginning of the same page. For example, if the starting address denoted by A23-A0 is 0000FEh, and three bytes of data are sent to the device, then the first two bytes of data will be programmed at addresses 0000FEh and 0000FFh while the last byte of data will be programmed at address 00000FL and 0000FFh while the last byte of data will be programmed at address 0000FL in the page (addresses 000001h through 0000FDh) will not be programmed and will remain in the erased state (FFh). In addition, if more than 256 bytes of data are sent to the device, then only the last 256 bytes sent will be latched into the internal buffer.

When the  $\overline{CS}$  pin is deasserted, the device will take the data stored in the internal buffer and program it into the appropriate memory array locations based on the starting address specified by A23-A0 and the number of data bytes sent to the device. If less than 256 bytes of data were sent to the device, then the remaining bytes within the page will not be programmed and will remain in the erased state (FFh). The programming of the data bytes is internally self-timed and should take place in a time of t<sub>PP</sub> or t<sub>BP</sub> if only programming a single byte.

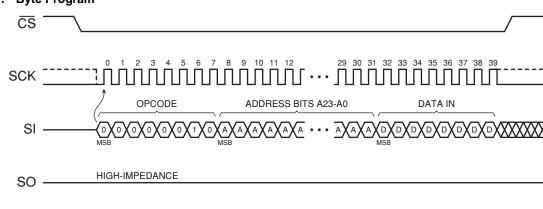
The three address bytes and at least one complete byte of data must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on even byte boundaries (multiples of eight bits); otherwise, the device will abort the operation and no data will be programmed into the memory array. In addition, if the memory is in the



protected state (see "Block Protection" on page 13), then the Byte/Page Program command will not be executed, and the device will return to the idle state once the  $\overline{CS}$  pin has been deasserted. The WEL bit in the Status Register will be reset back to the logical "0" state if the program cycle aborts due to an incomplete address being sent, an incomplete byte of data being sent, the  $\overline{CS}$  pin being deasserted on uneven byte boundaries, or because the memory location to be programmed is protected.

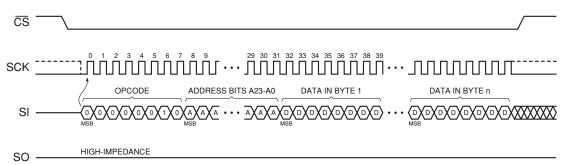
While the device is programming, the Status Register can be read and will indicate that the device is busy. For faster throughput, it is recommended that the Status Register be polled rather than waiting the  $t_{BP}$  or  $t_{PP}$  time to determine if the data bytes have finished programming. At some point before the program cycle completes, the WEL bit in the Status Register will be reset back to the logical "0" state.

The device also incorporates an intelligent programming algorithm that can detect when a byte location fails to program properly. If a programming error arises, it will be indicated by the EPE bit in the Status Register.



#### Figure 8-1. Byte Program

#### Figure 8-2. Page Program



### 8.2 Page Erase

The Page Erase command can be used to individually erase any page in the main memory array. The Main Memory Byte/Page Program command can be utilized at a later time.

To perform a Page Erase with the standard page size (256 bytes), an opcode of 81h must be clocked into the device followed by three address bytes comprised of eight dummy bits, 8 page address bits (PA7 - PA0) that specify the page in the main memory to be erased, and eight dummy bits.

When a low-to-high transition occurs on the  $\overline{CS}$  pin, the device will erase the selected page (the erased state is a Logic 1). The erase operation is internally self-timed and should take place in a maximum time of t<sub>PE</sub>. During this time, the RDY/BUSY bit in the Status Register will indicate that the device is busy.

The device also incorporates an intelligent erase algorithm that can detect when a byte location fails to erase properly. If an erase error arises, it will be indicated by the EPE bit in the Status Register.



### 8.3 Block Erase

A block of 4 or 32 Kbytes can be erased (all bits set to the logical "1" state) in a single operation by using one of three different opcodes for the Block Erase command. An opcode of 20h is used for a 4-Kbyte erase, and an opcode of 52h or D8h is used for a 32-Kbyte erase. Before a Block Erase command can be started, the Write Enable command must have been previously issued to the device to set the WEL bit of the Status Register to a logical "1" state.

To perform a Block Erase, the  $\overline{CS}$  pin must first be asserted and the appropriate opcode (20h, 52h, or D8h) must be clocked into the device. After the opcode has been clocked in, the three address bytes specifying an address within the 4- or 32-Kbyte block to be erased must be clocked in. Any additional data clocked into the device will be ignored. When the  $\overline{CS}$  pin is deasserted, the device will erase the appropriate block. The erasing of the block is internally self-timed and should take place in a time of  $t_{BLKE}$ .

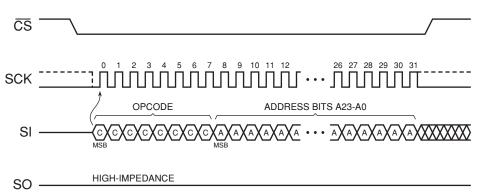
Since the Block Erase command erases a region of bytes, the lower order address bits do not need to be decoded by the device. Therefore, for a 4-Kbyte erase, address bits A11-A0 will be ignored by the device and their values can be either a logical "1" or "0". For a 32-Kbyte erase, address bits A14-A0 will be ignored by the device. Despite the lower order address bits not being decoded by the device, the complete three address bytes must still be clocked into the device before the CS pin is deasserted, and the CS pin must be deasserted on an even byte boundary (multiples of eight bits); otherwise, the device will abort the operation and no erase operation will be performed.

If the memory is in the protected state, then the Block Erase command will not be executed, and the device will return to the idle state once the  $\overline{CS}$  pin has been deasserted.

The WEL bit in the Status Register will be reset back to the logical "0" state if the erase cycle aborts due to an incomplete address being sent, the  $\overline{CS}$  pin being deasserted on uneven byte boundaries, or because a memory location within the region to be erased is protected.

While the device is executing a successful erase cycle, the Status Register can be read and will indicate that the device is busy. For faster throughput, it is recommended that the Status Register be polled rather than waiting the  $t_{BLKE}$  time to determine if the device has finished erasing. At some point before the erase cycle completes, the WEL bit in the Status Register will be reset back to the logical "0" state.

The device also incorporates an intelligent erase algorithm that can detect when a byte location fails to erase properly. If an erase error occurs, it will be indicated by the EPE bit in the Status Register.



#### Figure 8-3. Block Erase

### 8.4 Chip Erase

The entire memory array can be erased in a single operation by using the Chip Erase command. Before a Chip Erase command can be started, the Write Enable command must have been previously issued to the device to set the WEL bit of the Status Register to a logical "1" state.

Three opcodes (60h, 62h, and C7h) can be used for the Chip Erase command. There is no difference in device functionality when utilizing the three opcodes, so they can be used interchangeably. To perform a Chip Erase, one of the three opcodes must be clocked into the device. Since the entire memory array is to be erased, no address bytes need to be clocked into the device, and any data clocked in after the opcode will be ignored. When the CS pin is deasserted, the



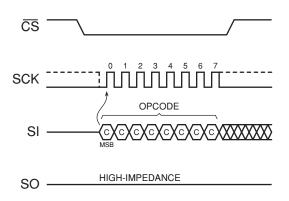
device will erase the entire memory array. The erasing of the device is internally self-timed and should take place in a time of  $t_{CHPE}$ .

The complete opcode must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on an even byte boundary (multiples of eight bits); otherwise, no erase will be performed. In addition, if the memory array is in the protected state, then the Chip Erase command will not be executed, and the device will return to the idle state once the  $\overline{CS}$  pin has been deasserted. The WEL bit in the Status Register will be reset back to the logical "0" state if the  $\overline{CS}$  pin is deasserted on uneven byte boundaries or if the memory is in the protected state.

While the device is executing a successful erase cycle, the Status Register can be read and will indicate that the device is busy. For faster throughput, it is recommended that the Status Register be polled rather than waiting the t<sub>CHPE</sub> time to determine if the device has finished erasing. At some point before the erase cycle completes, the WEL bit in the Status Register will be reset back to the logical "0" state.

The device also incorporates an intelligent erase algorithm that can detect when a byte location fails to erase properly. If an erase error occurs, it will be indicated by the EPE bit in the Status Register.

### Figure 8-4. Chip Erase



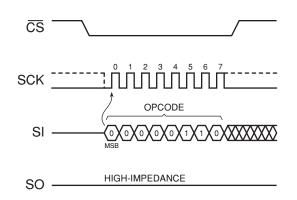
## 9. Protection Commands and Features

### 9.1 Write Enable

The Write Enable command is used to set the Write Enable Latch (WEL) bit in the Status Register to a logical "1" state. The WEL bit must be set before a Byte/Page Program, erase, Program OTP Security Register, or Write Status Register command can be executed. This makes the issuance of these commands a two step process, thereby reducing the chances of a command being accidentally or erroneously executed. If the WEL bit in the Status Register is not set prior to the issuance of one of these commands, then the command will not be executed.

To issue the Write Enable command, the  $\overline{CS}$  pin must first be asserted and the opcode of 06h must be clocked into the device. No address bytes need to be clocked into the device, and any data clocked in after the opcode will be ignored. When the  $\overline{CS}$  pin is deasserted, the WEL bit in the Status Register will be set to a logical "1". The complete opcode must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on an even byte boundary (multiples of eight bits); otherwise, the device will abort the operation and the state of the WEL bit will not change.



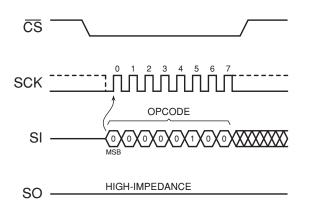


### 9.2 Write Disable

The Write Disable command is used to reset the Write Enable Latch (WEL) bit in the Status Register to the logical "0" state. With the WEL bit reset, all Byte/Page Program, erase, Program OTP Security Register, and Write Status Register commands will not be executed. Other conditions can also cause the WEL bit to be reset; for more details, refer to the WEL bit section of the Status Register description.

To issue the Write Disable command, the  $\overline{CS}$  pin must first be asserted and the opcode of 04h must be clocked into the device. No address bytes need to be clocked into the device, and any data clocked in after the opcode will be ignored. When the  $\overline{CS}$  pin is deasserted, the WEL bit in the Status Register will be reset to a logical "0". The complete opcode must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on an even byte boundary (multiples of eight bits); otherwise, the device will abort the operation and the state of the WEL bit will not change.

#### Figure 9-2. Write Disable



### 9.3 Block Protection

The device can be software protected against erroneous or malicious program or erase operations by utilizing the Block Protection feature of the device. Block Protection can be enabled or disabled by using the Write Status Register command to change the value of the Block Protection (BP0) bit in the Status Register. The following table outlines the two states of the BP0 bit and the associated protection area.



Protection Level	BP0	Protected Memory Address		
None	0	None		
Full Memory	1	00000h - 01FFFFh		



When the BP0 bit of the Status Register is in the logical "1" state, the entire memory array will be protected against program or erase operations. Any attempts to send a Byte/Page Program command, a Block Erase command, or a Chip Erase command will be ignored by the device.

As a safeguard against accidental or erroneous protecting or unprotecting of the memory array, the BP0 bit itself can be locked from updates by using the WP pin and the BPL (Block Protection Locked) bit of the Status Register (see "Protected States and the Write Protect Pin" on page 14 for more details).

The BP0 bit of the Status Register is a nonvolatile bit; therefore, the BP0 bit will retain its state even after the device has been power cycled. Care should be taken to ensure that BP0 is in the logical "1" state before powering down for those applications that wish to have the memory array fully protected upon power up. The default state for BP0 when shipped from Adesto is "0".

### 9.4 Protected States and the Write Protect Pin

The  $\overline{WP}$  pin is not linked to the memory array itself and has no direct effect on the protection status of the memory array. Instead, the  $\overline{WP}$  pin, in conjunction with the BPL (Block Protection Locked) bit in the Status Register, is used to control the hardware locking mechanism of the device. For hardware locking to be active, two conditions must be met-the  $\overline{WP}$  pin must be asserted and the BPL bit must be in the logical "1" state.

When hardware locking is active, the Block Protection (BP0) bit is locked and the BPL bit itself is also locked. Therefore, if the memory array is protected, it will be locked in the protected state, and if the memory array is unprotected, it will be locked in the unprotected state. These states cannot be changed as long as hardware locking is active, so the Write Status Register command will be ignored. In order to modify the protection status of the memory array, the WP pin must first be deasserted, and the BPL bit in the Status Register must be reset back to the logical "0" state using the Write Status Register command.

If the WP pin is permanently connected to GND, then once the BPL bit is set to a logical "1", the only way to reset the bit back to the logical "0" state is to power-cycle the device. This allows a system to power-up with all sectors software protected but not hardware locked. Therefore, sectors can be unprotected and protected as needed and then hardware locked at a later time by simply setting the BPL bit in the Status Register.

When the  $\overline{WP}$  pin is deasserted, or if the  $\overline{WP}$  pin is permanently connected to V<sub>CC</sub>, the BPL bit in the Status Register can be set to a logical "1", but doing so will not lock the BP0 bit.

Table 9-2 details the various protection and locking states of the device.

WP	BPL	Locking	BPL Change Allowed	BP0 and Protection Status
0	0		Can be modified from 0 to 1	BP0 bit unlocked and modifiable using the Write Status Register command. Memory array can be protected and unprotected freely.
0	1	Hardware Locked	Locked	BP0 bit locked in current state. The Write Status Register command will have no affect. Memory array is locked in current protected or unprotected state.
1	0		Can be modified from 0 to 1	BP0 bit unlocked and modifiable using the Write Status Register command. Memory array can be protected and unprotected freely.
1	1		Can be modified from 1 to 0	BP0 bit unlocked and modifiable using the Write Status Register command. Memory array can be protected and unprotected freely.

Table 9-2.	Hardware and Software Locking



## 10. Security Commands

## 10.1 Program OTP Security Register

The device contains a specialized OTP (One-Time Programmable) Security Register that can be used for purposes such as unique device serialization, system-level Electronic Serial Number (ESN) storage, locked key storage, etc. The OTP Security Register is independent of the main Flash memory array and is comprised of a total of 128 bytes of memory divided into two portions. The first 64 bytes (byte locations 0 through 63) of the OTP Security Register are allocated as a one-time user-programmable space. Once these 64 bytes have been programmed, they cannot be erased or reprogrammed. The remaining 64 bytes of the OTP Security Register (byte locations 64 through 127) are factory programmed by Adesto and will contain a unique value for each device. The factory programmed data is fixed and cannot be changed.

### Table 10-1. OTP Security Register

	Security Register Byte Number								
0	1		62	63	64	65		126	127
	One-Time User Programmable					Factory F	Programmed I	by Adesto	

The user-programmable portion of the OTP Security Register does not need to be erased before it is programmed. In addition, the Program OTP Security Register command operates on the entire 64-byte user-programmable portion of the OTP Security Register at one time. Once the user-programmable space has been programmed with any number of bytes, the user-programmable space cannot be programmed again; therefore, it is not possible to only program the first two bytes of the register and then program the remaining 62 bytes at a later time.

Before the Program OTP Security Register command can be issued, the Write Enable command must have been previously issued to set the WEL bit in the Status Register to a logical "1". To program the OTP Security Register, the CS pin must first be asserted and an opcode of 9Bh must be clocked into the device followed by the three address bytes denoting the first byte location of the OTP Security Register to begin programming at. Since the size of the user-programmable portion of the OTP Security Register is 64 bytes, the upper order address bits do not need to be decoded by the device. Therefore, address bits A23-A6 will be ignored by the device and their values can be either a logical "1" or "0". After the address bytes have been clocked in, data can then be clocked into the device and will be stored in the internal buffer.

If the starting memory address denoted by A23-A0 does not start at the beginning of the OTP Security Register memory space (A5-A0 are not all 0), then special circumstances regarding which OTP Security Register locations to be programmed will apply. In this situation, any data that is sent to the device that goes beyond the end of the 64-byte user-programmable space will wrap around back to the beginning of the OTP Security Register. For example, if the starting address denoted by A23-A0 is 00003Eh, and three bytes of data are sent to the device, then the first two bytes of data will be programmed at OTP Security Register addresses 00003Eh and 00003Fh while the last byte of data will be programmed at address 000000h. The remaining bytes in the OTP Security Register (addresses 000001h through 00003Dh) will not be programmed and will remain in the erased state (FFh). In addition, if more than 64 bytes of data are sent to the device, then only the last 64 bytes sent will be latched into the internal buffer.

When the  $\overline{CS}$  pin is deasserted, the device will take the data stored in the internal buffer and program it into the appropriate OTP Security Register locations based on the starting address specified by A23-A0 and the number of data bytes sent to the device. If less than 64 bytes of data were sent to the device, then the remaining bytes within the OTP Security Register will not be programmed and will remain in the erased state (FFh). The programming of the data bytes is internally self-timed and should take place in a time of t<sub>OTPP</sub>.

The three address bytes and at least one complete byte of data must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on even byte boundaries (multiples of eight bits); otherwise, the device will abort the operation and the user-programmable portion of the OTP Security Register will not be programmed. The

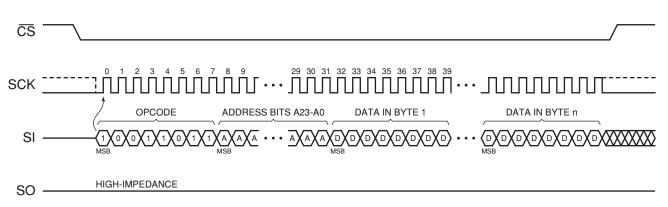


WEL bit in the Status Register will be reset back to the logical "0" state if the OTP Security Register program cycle aborts due to an incomplete address being sent, an incomplete byte of data being sent, the  $\overline{CS}$  pin being deasserted on uneven byte boundaries, or because the user-programmable portion of the OTP Security Register was previously programmed.

While the device is programming the OTP Security Register, the Status Register can be read and will indicate that the device is busy. For faster throughput, it is recommended that the Status Register be polled rather than waiting the t<sub>OTPP</sub> time to determine if the data bytes have finished programming. At some point before the OTP Security Register programming completes, the WEL bit in the Status Register will be reset back to the logical "0" state.

If the device is powered-down during the OTP Security Register program cycle, then the contents of the 64-byte user programmable portion of the OTP Security Register cannot be guaranteed and cannot be programmed again.

The Program OTP Security Register command utilizes the internal 256-buffer for processing. Therefore, the contents of the buffer will be altered from its previous state when this command is issued.



#### Figure 10-1. Program OTP Security Register

### 10.2 Read OTP Security Register

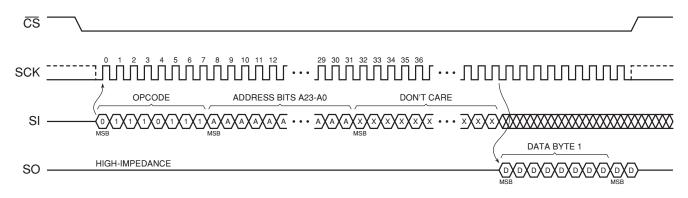
The OTP Security Register can be sequentially read in a similar fashion to the Read Array operation up to the maximum clock frequency specified by  $f_{CLK}$ . To read the OTP Security Register, the  $\overline{CS}$  pin must first be asserted and the opcode of 77h must be clocked into the device. After the opcode has been clocked in, the three address bytes must be clocked in to specify the starting address location of the first byte to read within the OTP Security Register. Following the three address bytes, two dummy bytes must be clocked into the device before data can be output.

After the three address bytes and the dummy bytes have been clocked in, additional clock cycles will result in OTP Security Register data being output on the SO pin. When the last byte (00007Fh) of the OTP Security Register has been read, the device will continue reading back at the beginning of the register (000000h). No delays will be incurred when wrapping around from the end of the register to the beginning of the register.

Deasserting the  $\overline{CS}$  pin will terminate the read operation and put the SO pin into a high-impedance state. The  $\overline{CS}$  pin can be deasserted at any time and does not require that a full byte of data be read.



Figure 10-2. Read OTP Security Register



## 11. Status Register Commands

### 11.1 Read Status Register

The Status Register can be read to determine the device's ready/busy status, as well as the status of many other functions such as Hardware Locking and Block Protection. The Status Register can be read at any time, including during an internally self-timed program or erase operation. The Status Register consists of two bytes.

To read the Status Register, the  $\overline{CS}$  pin must first be asserted and the opcode of 05h must be clocked into the device. After the opcode has been clocked in, the device will begin outputting Status Register data on the SO pin during every subsequent clock cycle. After the last bit (bit 0) of Status Register Byte 1 has been clocked out, the first bit (bit 7) of Status Register Byte 2 will be clocked out. After the last bit (bit 0) of Status Register Byte 2 has been clocked out, the sequence will repeat itself, starting again with bit 7 of Status Register Byte 1, as long as the  $\overline{CS}$  pin remains asserted and the clock pin is being pulsed. The data in the Status Register is constantly being updated, so each repeating sequence will output new data.

Deasserting the  $\overline{CS}$  pin will terminate the Read Status Register operation and put the SO pin into a high-impedance state. The  $\overline{CS}$  pin can be deasserted at any time and does not require that a full byte of data be read.

Bit <sup>(1)</sup>		Name	Type <sup>(2)</sup>		Description
7	BPL	Block Protection Locked	R/W	0	BP0 bit unlocked (default).
1	DFL	BIOCK PTOLECTION LOCKED	r/w	1	BP0 bit locked in current state when $\overline{\text{WP}}$ asserted.
6	RES	Reserved for future use	R	0	Reserved for future use.
5	EDE	Eross/Drogrom Error	P		Erase or program operation was successful.
5	EPE Erase/Program Error R	1	Erase or program error detected.		
4	WPP	Write Protect ( $\overline{WP}$ ) Pin Status	R	0	WP is asserted.
4	VVFF		ĸ	1	WP is deasserted.
3	RES	Reserved for future use	R	0	Reserved for future use.
2	2 BP0 Block Protection R/		R/W	0	Entire memory array is unprotected.
2	BFU	Block Protection	L/ A	1	Entire memory array is protected.

#### Table 11-1. Status Register Format



#### Table 11-1. Status Register Format

E	Bit <sup>(1)</sup>		Name	Type <sup>(2)</sup>	Description				
	1	WEL	Write Enable Latch Status	atus R		Device is not write enabled (default).			
	1	VVEL		R	1	Device is write enabled.			
	0 RDY/BSY		Ready/Busy Status	R	0	Device is ready.			
		ND I/DO I			1	Device is busy with an internal operation.			

Notes: 1. Only bits 7 and 2 of the Status Register can be modified when using the Write Status Register command.

2. R/W = Readable and writable

R = Readable only

### 11.1.1 BPL Bit

The BPL bit is used to control whether the Block Protection (BP0) bit can be modified or not. When the BPL bit is in the logical "1" state and the  $\overline{WP}$  pin is asserted, the BP0 bit will be locked and cannot be modified. The memory array will be locked in the current protected or unprotected state.

When the BPL bit is in the logical "0" state, the BP0 bit will be unlocked and can be modified. The BPL bit defaults to the logical "0" state after device power-up.

The BPL bit can be modified freely whenever the  $\overline{WP}$  pin is deasserted. However, if the  $\overline{WP}$  pin is asserted, then the BPL bit may only be changed from a logical "0" (BP0 bit unlocked) to a logical "1" (BP0 bit locked). In order to reset the BPL bit back to a logical "0" using the Write Status Register command, the  $\overline{WP}$  pin will have to first be deasserted.

The BPL and BP0 bits are the only bits of the Status Register that can be user modified via the Write Status Register command.

### 11.1.2 EPE Bit

The EPE bit indicates whether the last erase or program operation completed successfully or not. If at least one byte during the erase or program operation did not erase or program properly, then the EPE bit will be set to the logical "1" state. The EPE bit will not be set if an erase or program operation aborts for any reason such as an attempt to erase or program the memory when it is protected or if the WEL bit is not set prior to an erase or program operation. The EPE bit will be updated after every erase and program operation.

### 11.1.3 WPP Bit

The WPP bit can be read to determine if the  $\overline{WP}$  pin has been asserted or not.

### 11.1.4 BP0 Bit

The BP0 bits provides feedback on the software protection status for the device. In addition, the BP0 bit can also be modified to change the state of the software protection to allow the entire memory array to be protected or unprotected. When the BP0 bit is in the logical "0" state, then the entire memory array is unprotected. When the BP0 bit is in the logical "1" state, then the entire memory array and erase operations.

### 11.1.5 WEL Bit

The WEL bit indicates the current status of the internal Write Enable Latch. When the WEL bit is in the logical "0" state, the device will not accept any Byte/Page Program, erase, Program OTP Security Register, or Write Status Register commands. The WEL bit defaults to the logical "0" state after a device power-up or reset operation. In addition, the WEL bit will be reset to the logical "0" state automatically under the following conditions:

- Write Disable operation completes successfully
- Write Status Register operation completes successfully or aborts
- Program OTP Security Register operation completes successfully or aborts



- Byte/Page Program operation completes successfully or aborts
- Block Erase operation completes successfully or aborts
- Chip Erase operation completes successfully or aborts
- Hold condition aborts

If the WEL bit is in the logical "1" state, it will not be reset to a logical "0" if an operation aborts due to an incomplete or unrecognized opcode being clocked into the device before the  $\overline{CS}$  pin is deasserted. In order for the WEL bit to be reset when an operation aborts prematurely, the entire opcode for a Byte/Page Program, erase, Program OTP Security Register, or Write Status Register command must have been clocked into the device.

### 11.1.6 RDY/BSY Bit

The RDY/BSY bit is used to determine whether or not an internal operation, such as a program or erase, is in progress. To poll the RDY/BSY bit to detect the completion of a program or erase cycle, new Status Register data must be continually clocked out of the device until the state of the RDY/BSY bit changes from a logical "1" to a logical "0".Note that the RDY/BSY bit can be read either from Status Register Byte 1 or from Status Register Byte 2.

### 11.1.7 RSTE Bit

The RSTE bit is used to enable or disable the Reset command. When the RSTE bit is in the Logical 0 state (the default state after power-up), the Reset command is disabled and any attempts to reset the device using the Reset command will be ignored. When the RSTE bit is in the Logical 1 state, the Reset command is enabled.

The RSTE bit will retain its state as long as power is applied to the device. Once set to the Logical 1 state, the RSTE bit will remain in that state until it is modified using the Write Status Register Byte 2 command or until the device has been power cycled. The Reset command itself will not change the state of the RSTE bit.

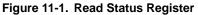
Bit <sup>(1)</sup>		Name	Type <sup>(2)</sup>		Description		
7	RES	Reserved for future use	R	0	Reserved for future use		
6	RES	Reserved for future use	R	0	Reserved for future use		
5	RES	Reserved for future use	R	0 Reserved for future use			
4	RSTE	Reset Enabled			Reset command is disabled (default)		
4	KOTE	Reset Ellabled	Γ./ V V	1	Reset command is enabled		
3	RES	Reserved for future use	R	0	Reserved for future use		
2	RES	Reserved for future use	R	0	Reserved for future use		
1	RES	Reserved for future use	R	0	Reserved for future use		
0	0 RDY/BSY Ready/Busy Status		R	0	Device is ready		
0	RU1/B31	Ready/Busy Status	IX .	1	Device is busy with an internal operation		

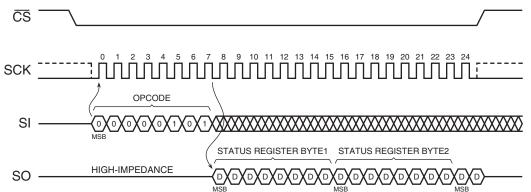
#### Table 11-2. Status Register Format – Byte 2

Note: 1. Only bits 4 and 3 of Status Register Byte 2 will be modified when using the Write Status Register Byte 2 command

 R/W = Readable and Writeable R = Readable only.







### 11.2 Write Status Register

The Write Status Register command is used to modify the BPL bit and the BP0 bit of the Status Register. Before the Write Status Register command can be issued, the Write Enable command must have been previously issued to set the WEL bit in the Status Register to a logical "1".

To issue the Write Status Register command, the  $\overline{CS}$  pin must first be asserted and the opcode of 01h must be clocked into the device followed by one byte of data. The one byte of data consists of the BPL bit value, four don't care bits, the BPO bit value, and two additional don't care bits (see Table 11-3). Any additional data bytes that are sent to the device will be ignored. When the  $\overline{CS}$  pin is deasserted, the BPL bit and the BPO bit in the Status Register will be modified, and the WEL bit in the Status Register will be reset back to a logical "0". The value of BPO and the state of the BPL bit and the  $\overline{WP}$  pin before the Write Status Register command was executed (the prior state of the BPL bit and the state of the  $\overline{WP}$ pin when the  $\overline{CS}$  pin is deasserted) will determine whether or not software protection will be changed. Please refer to Section 9.4, "Protected States and the Write Protect Pin" on page 14 for more details.

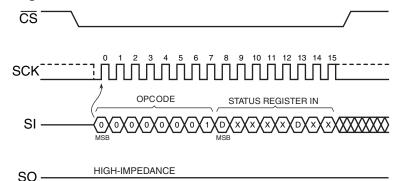
The complete one byte of data must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on even byte boundaries (multiples of eight bits); otherwise, the device will abort the operation, the state of the BPL and BP0 bits will not change, memory protection status will not change, and the WEL bit in the Status Register will be reset back to the logical "0" state.

If the  $\overline{WP}$  pin is asserted, then the BPL bit can only be set to a logical "1". If an attempt is made to reset the BPL bit to a logical "0" while the  $\overline{WP}$  pin is asserted, then the Write Status Register Byte command will be ignored, and the WEL bit in the Status Register will be reset back to the logical "0" state. In order to reset the BPL bit to a logical "0", the  $\overline{WP}$  pin must be deasserted.

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
BPL	Х	Х	Х	Х	BP0	Х	Х

#### Table 11-3. Write Status Register Format





### 11.3 Write Status Register Byte 2

The Write Status Register Byte 2 command is used to modify the RSTE. Using the Write Status Register Byte 2 command is the only way to modify the RSTE in the Status Register during normal device operation. Before the Write Status Register Byte 2 command can be issued, the Write Enable command must have been previously issued to set the WEL bit in the Status Register to a Logical 1.

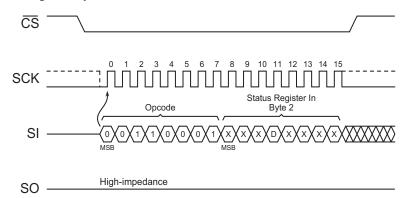
To issue the Write Status Register Byte 2 command, the  $\overline{CS}$  pin must first be asserted and then the opcode 31h must be clocked into the device followed by one byte of data. The one byte of data consists of three don't-care bits, the RSTE bit value, and four additional don't-care bits (see Table 11-4). Any additional data bytes sent to the device will be ignored. When the  $\overline{CS}$  pin is deasserted, the RSTE bit in the Status Register will be modified, and the WEL bit in the Status Register will be reset back to a Logical 0.

The complete one byte of data must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on even byte boundaries (multiples of eight bits); otherwise, the device will abort the operation, the state of the RSTE bit will not change, and the WEL bit in the Status Register will be reset back to the Logical 0 state.

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Х	Х	Х	RSTE	Х	Х	Х	Х

#### Table 11-4. Write Status Register Byte 2 Format

Figure 11-3. Write Status Register Byte 2





## 12. Other Commands and Functions

### 12.1 Read Manufacturer and Device ID

Identification information can be read from the device to enable systems to electronically query and identify the device while it is in system. The identification method and the command opcode comply with the JEDEC standard for "Manufacturer and Device ID Read Methodology for SPI Compatible Serial Interface Memory Devices". The type of information that can be read from the device includes the JEDEC defined Manufacturer ID, the vendor specific Device ID, and the vendor specific Extended Device Information.

Since not all Flash devices are capable of operating at very high clock frequencies, applications should be designed to read the identification information from the devices at a reasonably low clock frequency to ensure all devices used in the application can be identified properly. Once the identification process is complete, the application can increase the clock frequency to accommodate specific Flash devices that are capable of operating at the higher clock frequencies.

To read the identification information, the  $\overline{CS}$  pin must first be asserted and the opcode of 9Fh must be clocked into the device. After the opcode has been clocked in, the device will begin outputting the identification data on the SO pin during the subsequent clock cycles. The first byte that will be output will be the Manufacturer ID followed by two bytes of Device ID information. The fourth byte output will be the Extended Device Information String Length, which will be 00h indicating that no Extended Device Information follows. After the Extended Device Information String Length byte is output, the SO pin will go into a high-impedance state; therefore, additional clock cycles will have no affect on the SO pin and no data will be output. As indicated in the JEDEC standard, reading the Extended Device Information String Length and any subsequent data is optional.Deasserting the  $\overline{CS}$  pin will terminate the Manufacturer and Device ID read operation and put the SO pin into a high-impedance state. The  $\overline{CS}$  pin can be deasserted at any time and does not require that a full byte of data be read.

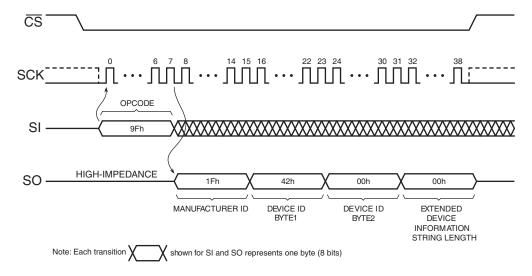
Byte No.	Data Type	Value
1	Manufacturer ID	1Fh
2	Device ID (Part 1)	42h
3	Device ID (Part 2)	00h
4	Extended Device Information String Length	00h

### Table 12-1. Manufacturer and Device ID Information

#### Table 12-2. Manufacturer and Device ID Details

Data Type	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Hex Value	Details			
Manufacturer ID		JEDEC Assigned Code						1Fh	IEDEC Code: 0001 1111 (1Eb for Adopto)				
Manufacturer ID	0	0	0	1	1	1	1	1		JEDEC Code: 0001 1111 (1Fh for Adesto)			
Device ID (Part	F	amily Co	de	Density Code				42h	Family Code: 010 (AT25F/AT25FSxxx series)				
1)	0	1	0	0	0	0	1	0	4211	Density Code: 00010 (1-Mbit)			
Device ID (Part	-	Sub Code			Product Version Code				00h	Sub Code: 000 (Standard series)			
2)	0	0	0	0	0	0	0	0	UUN	Product Version:00000			



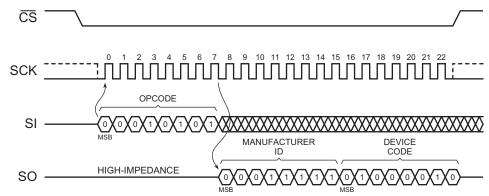


## 12.2 Read ID (Legacy Command)

Identification information can be read from the device to enable systems to electronically query and identify the device while it is in system. The preferred method for doing so is the JEDEC standard "Read Manufacturer and Device ID" method described in Section 12.1 on page 22; however, the legacy Read ID command is supported on the AT25DF011 to enable backwards compatibility to previous generation devices.

To read the identification information, the  $\overline{CS}$  pin must first be asserted and the opcode of 15h must be clocked into the device. After the opcode has been clocked in, the device will begin outputting the identification data on the SO pin during the subsequent clock cycles. The first byte that will be output will be the Manufacturer ID of 1Fh followed by a single byte of data representing a device code of 65h. After the device code is output, the SO pin will go into a high-impendance state; therefore, additional clock cycles will have no affect on the SO pin and no data will be output.

Deasserting the  $\overline{CS}$  pin will terminate the Read ID operation and put the SO pin into a high-impedance state. The  $\overline{CS}$  pin can be deasserted at any time and does not require that a full byte of data read.



### Figure 12-2. Read ID (Legacy Command)

### 12.3 Deep Power-Down

During normal operation, the device will be placed in the standby mode to consume less power as long as the  $\overline{CS}$  pin remains deasserted and no internal operation is in progress. The Deep Power-Down command offers the ability to place the device into an even lower power consumption state called the Deep Power-Down mode.



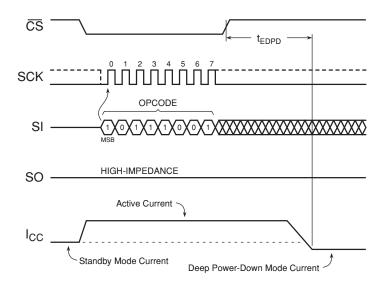
When the device is in the Deep Power-Down mode, all commands including the Read Status Register command will be ignored with the exception of the Resume from Deep Power-Down command. Since all commands will be ignored, the mode can be used as an extra protection mechanism against program and erase operations.

Entering the Deep Power-Down mode is accomplished by simply asserting the  $\overline{CS}$  pin, clocking in the opcode of B9h, and then deasserting the  $\overline{CS}$  pin. Any additional data clocked into the device after the opcode will be ignored. When the  $\overline{CS}$  pin is deasserted, the device will enter the Deep Power-Down mode within the maximum time of t<sub>EDPD</sub>.

The complete opcode must be clocked in before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on an even byte boundary (multiples of eight bits); otherwise, the device will abort the operation and return to the standby mode once the  $\overline{CS}$  pin is deasserted. In addition, the device will default to the standby mode after a power-cycle.

The Deep Power-Down command will be ignored if an internally self-timed operation such as a program or erase cycle is in progress. The Deep Power-Down command must be reissued after the internally self-timed operation has been completed in order for the device to enter the Deep Power-Down mode.

#### Figure 12-3. Deep Power-Down



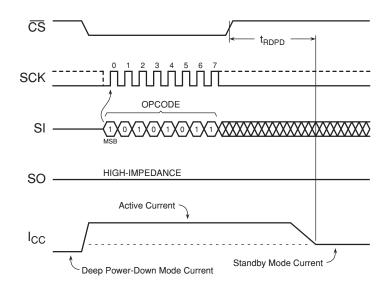
### 12.4 Resume from Deep Power-Down

In order to exit the Deep Power-Down mode and resume normal device operation, the Resume from Deep Power-Down command must be issued. The Resume from Deep Power-Down command is the only command that the device will recognized while in the Deep Power-Down mode.

To resume from the Deep Power-Down mode, the  $\overline{CS}$  pin must first be asserted and opcode of ABh must be clocked into the device. Any additional data clocked into the device after the opcode will be ignored. When the  $\overline{CS}$  pin is deasserted, the device will exit the Deep Power-Down mode within the maximum time of t<sub>RDPD</sub> and return to the standby mode. After the device has returned to the standby mode, normal command operations such as Read Array can be resumed.

If the complete opcode is not clocked in before the CS pin is deasserted, or if the CS pin is not deasserted on an even byte boundary (multiples of eight bits), then the device will abort the operation and return to the Deep Power-Down mode.

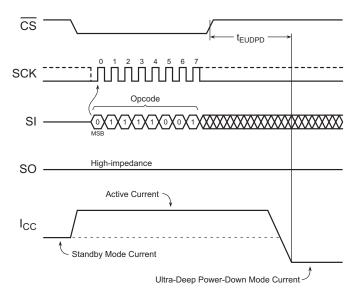




### 12.5 Ultra-Deep Power-Down

The Ultra-Deep Power-Down mode allows the device to further reduce its energy consumption compared to the existing standby and Deep Power-Down modes by shutting down additional internal circuitry. When the device is in the Ultra-Deep Power-Down mode, all commands including the Status Register Read and Resume from Deep Power-Down commands will be ignored. Since all commands will be ignored, the mode can be used as an extra protection mechanism against inadvertent or unintentional program and erase operations. Entering the Ultra-Deep Power-Down mode is accomplished by simply asserting the  $\overline{CS}$  pin, clocking in the opcode 79h, and then deasserting the  $\overline{CS}$  pin. Any additional data clocked into the device after the opcode will be ignored. When the  $\overline{CS}$  pin is deasserted, the device will enter the Ultra-Deep Power-Down mode within the maximum time of  $t_{EUPPD}$ 

The complete opcode must be clocked in before the  $\overline{CS}$  pin is deasserted; otherwise, the device will abort the operation and return to the standby mode once the  $\overline{CS}$  pin is deasserted. In addition, the device will default to the standby mode after a power cycle. The Ultra-Deep Power-Down command will be ignored if an internally self-timed operation such as a program or erase cycle is in progress.



#### Figure 12-5. Ultra-Deep Power-Down



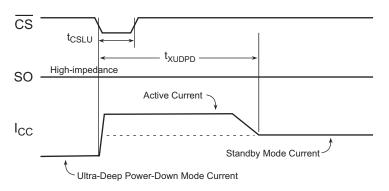
## 12.6 Exit Ultra-Deep Power-Down

To exit from the Ultra-Deep Power-Down mode, any one of three operations can be performed:

### Chip Select Toggle

The  $\overline{CS}$  pin must simply be pulsed by asserting the  $\overline{CS}$  pin, waiting the minimum necessary  $t_{CSLU}$  time, and then deasserting the  $\overline{CS}$  pin again. To facilitate simple software development, a dummy byte opcode can also be entered while the  $\overline{CS}$  pin is being pulsed; the dummy byte opcode is simply ignored by the device in this case. After the  $\overline{CS}$  pin has been deasserted, the device will exit from the Ultra-Deep Power-Down mode and return to the standby mode within a maximum time of  $t_{XUDPD}$  If the  $\overline{CS}$  pin is reasserted before the  $t_{XUDPD}$  time has elapsed in an attempt to start a new operation, then that operation will be ignored and nothing will be performed.

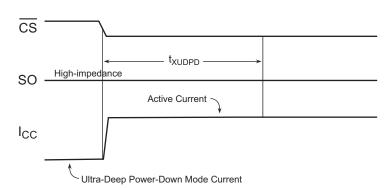
### Figure 12-6. Exit Ultra-Deep Power-Down (Chip Select Toggle)



### Chip Select Low

By asserting the  $\overline{CS}$  pin, waiting the minimum necessary  $t_{XUDPD}$  time, and then clocking in the first bit of the next Opcode command cycle. If the first bit of the next command is clocked in before the  $t_{XUDPD}$  time has elapsed, the device will exit Ultra Deep Power Down, however the intended operation will be ignored.

#### Figure 12-7. Exit Ultra-Deep Power-Down (Chip Select Low)



### Power Cycling

The device can also exit the Ultra Deep Power Mode by power cycling the device. The system must wait for the device to return to the standby mode before normal command operations can be resumed. Upon recovery from Ultra Deep Power Down all internal registers will be at there Power-On default state.



### 12.7 Hold

The HOLD pin is used to pause the serial communication with the device without having to stop or reset the clock sequence. The Hold mode, however, does not have an affect on any internally self-timed operations such as a program or erase cycle. Therefore, if an erase cycle is in progress, asserting the HOLD pin will not pause the operation, and the erase cycle will continue until it is finished.

The Hold mode can only be entered while the  $\overline{CS}$  pin is asserted. The Hold mode is activated simply by asserting the HOLD pin during the SCK low pulse. If the HOLD pin is asserted during the SCK high pulse, then the Hold mode won't be started until the beginning of the next SCK low pulse. The device will remain in the Hold mode as long as the HOLD pin and  $\overline{CS}$  pin are asserted.

While in the Hold mode, the SO pin will be in a high-impedance state. In addition, both the SI pin and the SCK pin will be ignored. The  $\overline{WP}$  pin, however, can still be asserted or deasserted while in the Hold mode.

To end the Hold mode and resume serial communication, the  $\overline{HOLD}$  pin must be deasserted during the SCK low pulse. If the  $\overline{HOLD}$  pin is deasserted during the SCK high pulse, then the Hold mode won't end until the beginning of the next SCK low pulse.

If the  $\overline{CS}$  pin is deasserted while the  $\overline{HOLD}$  pin is still asserted, then any operation that may have been started will be aborted, and the device will reset the WEL bit in the Status Register back to the logical "0" state.

# 

### Figure 12-8. Hold Mode

### 12.8 Reset

In some applications, it may be necessary to prematurely terminate a program or erase operation rather than wait the hundreds of microseconds or milliseconds necessary for the program or erase operation to complete normally. The Reset command allows a program or erase operation in progress to be ended abruptly and returns the device to an idle state. Since the need to reset the device is immediate, the Write Enable command does not need to be issued prior to the Reset command. Therefore, the Reset command operates independently of the state of the WEL bit in the Status Register.

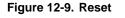
The Reset command can be executed only if the command has been enabled by setting the Reset Enabled (RSTE) bit in the Status Register to a Logical 1 using write status register byte 2 command 31h. This command should be entered before a program command is entered. If the Reset command has not been enabled (the RSTE bit is in the Logical 0 state), then any attempts at executing the Reset command will be ignored.

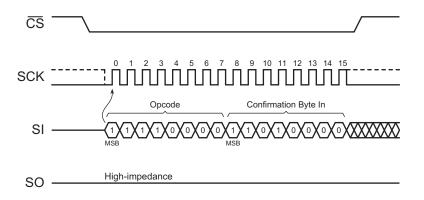
To perform a Reset, the  $\overline{CS}$  pin must first be asserted, and then the opcode F0h must be clocked into the device. No address bytes need to be clocked in, but a confirmation byte of D0h must be clocked into the device immediately after the opcode. Any additional data clocked into the device after the confirmation byte will be ignored. When the  $\overline{CS}$  pin is deasserted, the program operation currently in progress will be terminated within a time of t<sub>SWRST</sub>. Since the program or erase operation may not complete before the device is reset, the contents of the page being programmed or erased cannot be guaranteed to be valid.



The Reset command has no effect on the states of the Configuration Register or RSTE bit in the Status Register. The WEL however, will be reset back to its default state.

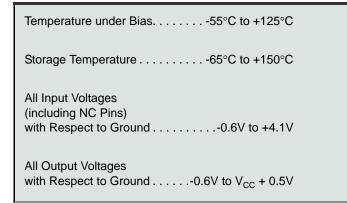
The complete opcode and confirmation byte must be clocked into the device before the  $\overline{CS}$  pin is deasserted, and the  $\overline{CS}$  pin must be deasserted on an even byte boundary (multiples of eight bits); otherwise, no Reset operation will be performed.





## **13. Electrical Specifications**

## 13.1 Absolute Maximum Ratings\*



\*Notice: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## 13.2 DC and AC Operating Range

		AT25DF011
Operating Temperature (Case) <sup>(1)</sup>	Ind.	-40°C to 85°C
V <sub>CC</sub> Power Supply		1.65V to 3.6V

1. Temperature Range:-10°C to +85°C (1.65V to 3.6V), -40°C to +85° (1.7V to 3.6V)



## 13.3 DC Characteristics

			1.6	5V to 3.6	SV .	2.3	3V to 3.6	V	
Symbol	Parameter	Condition	Min	Тур	Max	Min	Тур	Мах	Units
I <sub>UDPD</sub>	Ultra-Deep Power- Down Current	$\overline{CS} = V_{CC.}$ All other inputs at 0V or $V_{CC}$		0.2	1		0.3	1	μΑ
I <sub>DPD</sub> <sup>(1)</sup>	Deep Power-Down Current	CS, HOLD, WP = V <sub>IH</sub> All inputs at CMOS levels		5	15		8.5	15	μA
I <sub>SB</sub>	Standby Current	$\overline{CS}$ , $\overline{HOLD}$ , $\overline{WP} = V_{IH}$ All inputs at CMOS levels		25	40		25	40	μA
I <sub>CC1</sub> <sup>(2)(3)</sup>	Active Current, Low	f = 1MHz; I <sub>OUT</sub> = 0mA		4.5	9		5.5	9	mA
	Power Read (03h, 0Bh) Operation	f = 20MHz; I <sub>OUT</sub> = 0mA		4.5	9		5.5	9	mA
(2)(3)	Active Current,	f = 50MHz; I <sub>OUT</sub> = 0mA		5	10		6	10	mA
I <sub>CC2</sub>	Read Operation	f = 85MHz; I <sub>OUT</sub> = 0mA		5	10		6	10	mA
I <sub>CC3</sub> <sup>(2)(3)</sup>	Active Current, Program Operation	$\overline{\text{CS}} = \text{V}_{\text{CC}}$		12	16		12	16	mA
I <sub>CC4</sub> <sup>(2)(3)</sup>	Active Current, Erase Operation	$\overline{\text{CS}} = \text{V}_{\text{CC}}$		12	18		12	18	mA
I <sub>LI</sub>	Input Load Current	All inputs at CMOS levels			1			1	μA
I <sub>LO</sub>	Output Leakage Current	All inputs at CMOS levels			1			1	μA
V <sub>IL</sub>	Input Low Voltage				V <sub>CC</sub> x 0.2			V <sub>CC</sub> x 0.3	V
V <sub>IH</sub>	Input High Voltage		V <sub>CC</sub> x 0.8			V <sub>CC</sub> x 0.7			V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 100μA			0.2			0.4	V
V <sub>OH</sub>	Output High Voltage	Ι <sub>ΟΗ</sub> = -100μΑ	V <sub>CC</sub> - 0.2V			V <sub>CC</sub> - 0.2V			V

Notes: 1. Max. specification is 20µA @ 85°C.

2. Typical values measured at 1.8V @ 25°C for the 1.65V to 3.6V range.

3. Typical values measured at 3.0V @ 25°C for the 2.3V to 3.6V range.

## 13.4 AC Characteristics - Maximum Clock Frequencies

		1.	65V to 3.6	δV	2			
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Units
f <sub>CLK</sub>	Maximum Clock Frequency for All Operations (including 0Bh opcode)			104			104	MHz
f <sub>RDLF</sub>	Maximum Clock Frequency for 03h Opcode (Read Array – Low Frequency)			33			33	MHz
f <sub>RDDO</sub>	Maximum Clock Frequency for 3B Opcode			50			50	MHz



## 13.5 AC Characteristics – All Other Parameters

		1.	65V to 3.6	6V		V		
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Units
t <sub>CLKH</sub>	Clock High Time	4			4			ns
t <sub>CLKL</sub>	Clock Low Time	4			4			ns
t <sub>CLKR</sub> <sup>(1)</sup>	Clock Rise Time, Peak-to-Peak (Slew Rate)	0.1			0.1			V/ns
t <sub>CLKF</sub> <sup>(1)</sup>	Clock Fall Time, Peak-to-Peak (Slew Rate)	0.1			0.1			V/ns
t <sub>CSH</sub>	Chip Select High Time	35			25			ns
t <sub>CSLS</sub>	Chip Select Low Setup Time (relative to Clock)	6			6			ns
t <sub>CSLH</sub>	Chip Select Low Hold Time (relative to Clock)	6			6			ns
t <sub>CSHS</sub>	Chip Select High Setup Time (relative to Clock)	6			6			ns
t <sub>CSHH</sub>	Chip Select High Hold Time (relative to Clock)	6			6			ns
t <sub>DS</sub>	Data In Setup Time	2			2			ns
t <sub>DH</sub>	Data In Hold Time	1			1			ns
t <sub>DIS</sub> <sup>(1)</sup>	Output Disable Time			8			6	ns
t <sub>v</sub>	Output Valid Time			8			6	ns
t <sub>OH</sub>	Output Hold Time	0			0			ns
t <sub>HLS</sub>	HOLD Low Setup Time (relative to Clock)	6			5			ns
t <sub>HLH</sub>	HOLD Low Hold Time (relative to Clock)	6			5			ns
t <sub>HHS</sub>	HOLD High Setup Time (relative to Clock)	6			5			ns
t <sub>HHH</sub>	HOLD High Hold Time (relative to Clock)	6			5			ns
t <sub>HLQZ</sub> <sup>(1)</sup>	HOLD Low to Output High-Z			7			6	ns
t <sub>HHQX</sub> <sup>(1)</sup>	HOLD High to Output Low-Z			7			6	ns
t <sub>WPS</sub> <sup>(1)(2)</sup>	Write Protect Setup Time	20			20			ns
t <sub>WPH</sub> <sup>(1)(2)</sup>	Write Protect Hold Time	100			100			ns
t <sub>EDPD</sub> <sup>(1)</sup>	Chip Select High to Deep Power-Down			2			2	μs
t <sub>EUDPD</sub> .	Chip Select High to Ultra Deep Power-Down			3			3	μs
t <sub>SWRST</sub>	Software Reset Time			60			60	μs
t <sub>CSLU</sub>	Minimum Chip Select Low to Exit Ultra Deep Power-Down	20			20			ns
t <sub>XUDPD</sub>	Exit Ultra Deep Power-Down Time	70			70			μs
t <sub>RDPD</sub> <sup>(1)</sup>	Chip Select High to Standby Mode			8			8	μs

Notes: 1. Not 100% tested (value guaranteed by design and characterization).

2. Only applicable as a constraint for the Write Status Register command when BPL = 1.



## 13.6 Program and Erase Characteristics

	Parameter			.65V-3.6	v	2.3V-3.6V			
Symbol				Тур	Max	Min	Тур	Мах	Units
t <sub>PP</sub> <sup>(1)</sup>	Page Program Time (256 Bytes)		1.5	3.5		1.5	3.5	ms	
t <sub>BP</sub>	Byte Program Time		12			8		μs	
t <sub>PE</sub>	Page Erase Time			6	25		6	25	ms
t <sub>BLKE</sub> <sup>(1)</sup>	Block Erase Time	4 Kbytes		50	75		50	60	ms
BLKE		32 Kbytes		350	600		300	400	
t <sub>CHPE</sub> <sup>(1)(2)</sup>	Chip Erase Time			1400	2300		1200	1600	ms
t <sub>OTPP</sub> <sup>(1)</sup>	OTP Security Register Program Time			400	950		400	950	μs
t <sub>WRSR</sub> <sup>(2)</sup>	Write Status Register Time			20	40		20	40	ms

Note: 1. Maximum values indicate worst-case performance after 100,000 erase/program cycles.

2. Not 100% tested (value guaranteed by design and characterization).

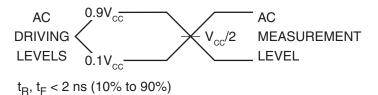
3. Program and Erase operations characterized at -10°C to +85°C. Program and Erase operations at -40°C to -10°C require a minimum of 1.7V.

## 13.7 Power-up Conditions

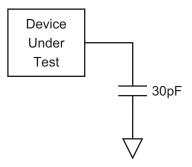
		1.65V-3.6V		
Symbol	Parameter	Min	Max	Units
t <sub>VCSL</sub>	Minimum $V_{CC}$ to Chip Select Low Time	70		μs
t <sub>PUW</sub>	Power-up Device Delay Before Program or Erase Allowed		5	ms
V <sub>POR</sub>	Power-on Reset Voltage	1.45	1.6	V



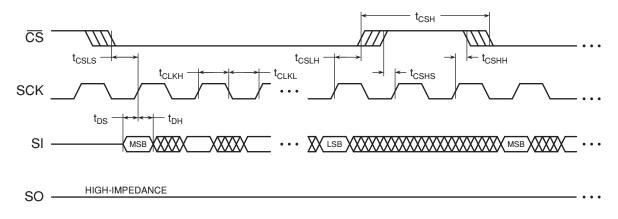
### 13.8 Input Test Waveforms and Measurement Levels



### 13.9 Output Test Load



## 14. AC Waveforms



### Figure 14-1. Serial Input Timing

#### Figure 14-2. Serial Output Timing

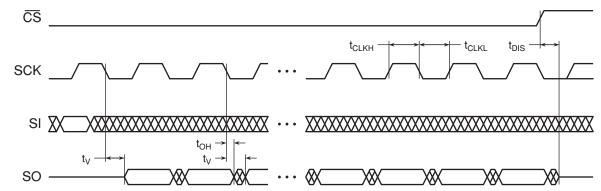
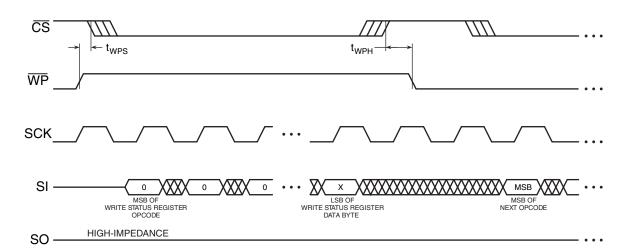
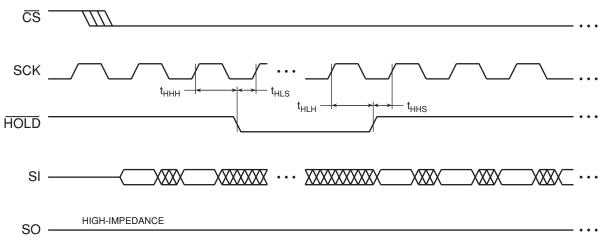




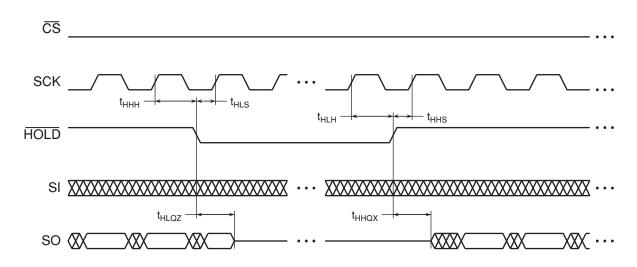
Figure 14-3. WP Timing for Write Status Register Command When BPL = 1



### Figure 14-4. HOLD Timing – Serial Input



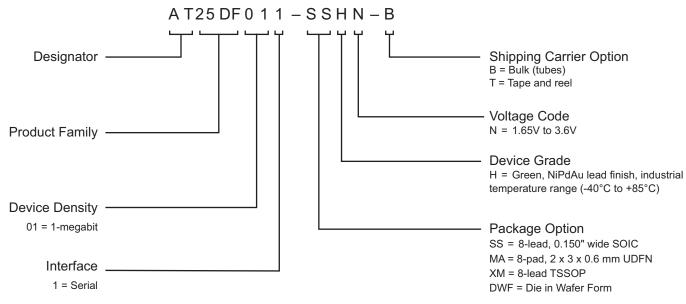






## 15. Ordering Information

## 15.1 Ordering Code Detail



## 15.2 Green Package Options (Pb/Halide-free/RoHS Compliant)

Ordering Code <sup>(1)</sup>	Package	Lead Finish	Operating Voltage	Max. Freq. (MHz)	Operation Range	
AT25DF011-SSHN-B AT25DF011-SSHN-T	8S1		1.65V to 3.6V <sup>(2)</sup>	104		
AT25DF011-MAHN-T	8MA3	NiPdAu			Industrial (-40°C to +85°C) <sup>(2)</sup>	
AT25DF011-XMHN-B AT25DF011-XMHN-T	8X					
AT25DF011-DWF (3)	DWF					

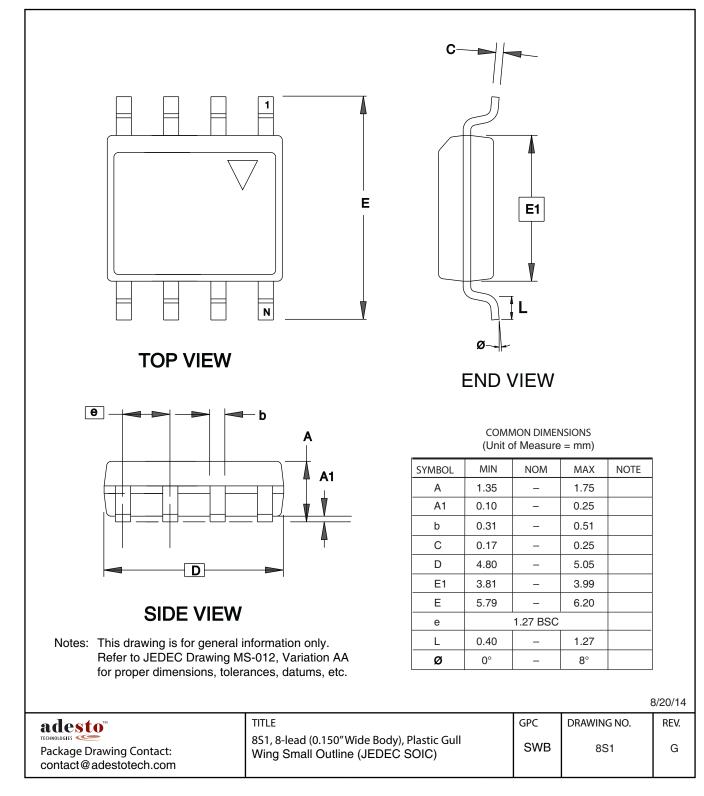
- 1. The shipping carrier option code is not marked on the devices.
- 2. Temperature Range:-10°C to +85°C (1.65V to 3.6V), -40°C to +85° (1.7V to 3.6V).
- 3. Contact Adesto for mechanical drawing or Die Sales information.

Package Type			
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)		
8MA3	8-pad, 2 x 3 x 0.6 mm, Thermally Enhanced Plastic Ultra Thin Dual Flat No Lead Package (UDFN)		
8X	8-lead, Thin Small Outline Package		
DWF	Die in Wafer Form		



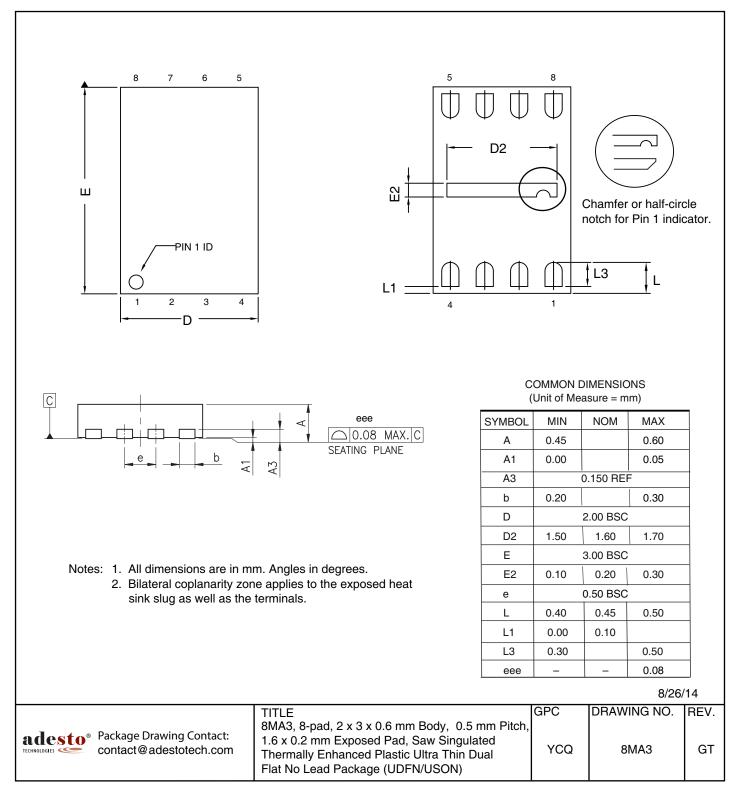
## 16. Packaging Information

### 16.1 8S1 – JEDEC SOIC



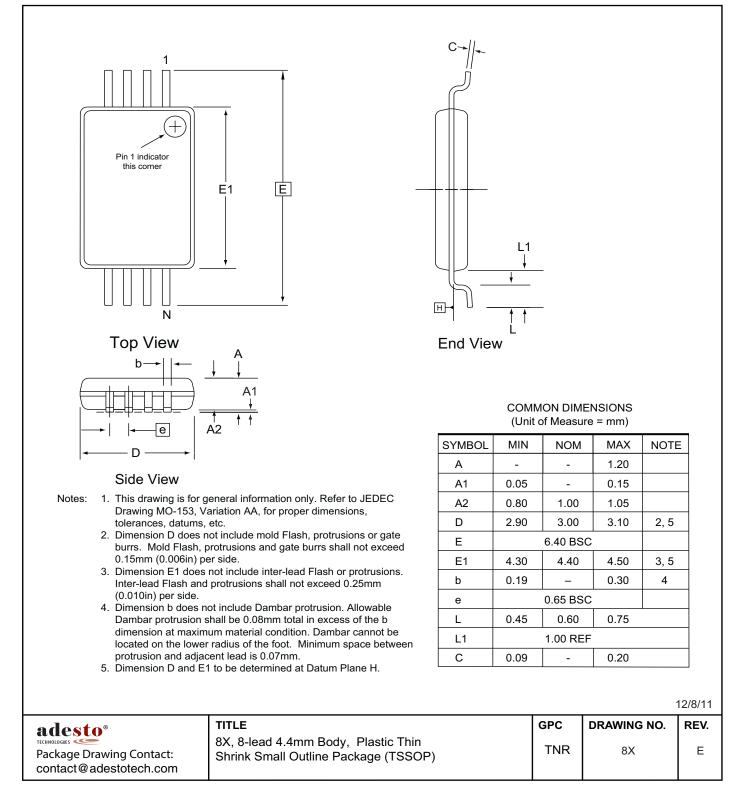


### 16.2 8MA3 – UDFN





### 16.3 8X-TSSOP





## 17. Revision History

Revision Level – Release Date	History	
A – April 2014	Initial release. Document posted to public website.	
B – October 2014	Corrected last byte address in sections 6, 7.1, and 7.2. Corrected 8S1 and 8MA3 package outline drawings. Updated I <sub>UDPD</sub> description in Table 13.3. Corrected product density error on Ordering Detail diagram.Updated Table 9-1 (Protected Memory Address). Removed tray shipping option, Updated AC and DC specifications.	
C – February 2015	Added Die in Wafer Form (DWF) ordering option. Added I <sub>DPD</sub> specification footnote.	





### **Corporate Office**

California | USA Adesto Headquarters 1250 Borregas Avenue Sunnyvale, CA 94089 Phone: (+1) 408.400.0578 Email: contact@adestotech.com

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